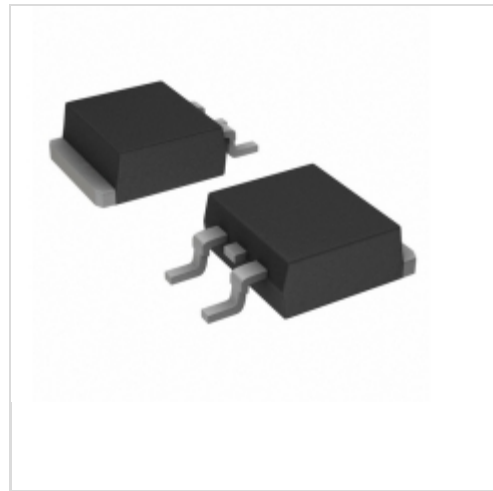


## UGB8CT-E3/81



Vishay / Semiconductor - Diodes Division

DIODE GEN PURP 150V 8A TO263AB

Lead free / RoHS Compliant

Discrete Semiconductor Products

[UGB8CT-E3/81.pdf](#)

**Buy Now**

**Out Stock**

**0 pcs**

Minimum:1

Multiples:100

Manufacturer lead time 10 weeks

We can supply Vishay / Semiconductor - Diodes Division UGB8CT-E3/81, use the request quote form to request UGB8CT-E3/81 price, Vishay / Semiconductor - Diodes Division Datasheet PDF and lead time. Zeanoit.com is a professional electronic components distributor. With 3+ Million line items of available electronic components can ship in short lead-time, over 250 thousand part numbers of electronic components in stock for immediately delivery, which may include part number UGB8CT-E3/81. The price and lead time for UGB8CT-E3/81 depending on the quantity required, availability and warehouse location.

### Shopping Process

**1**

Confirm the product

**2**

submit the order

**3**

payment

**4**

wait for delivery

**5**

receive the goods

### Specifications

<b>Voltage - Forward (Vf) (Max) @ If:</b>	1V @ 8A
<b>Voltage - DC Reverse (Vr) (Max):</b>	150V
<b>Supplier Device Package:</b>	TO-263AB
<b>Speed:</b>	Fast Recovery = 200mA (Io)
<b>Series:</b>	-
<b>Reverse Recovery Time (trr):</b>	30ns
<b>Packaging:</b>	Tape & Reel (TR)
<b>Package / Case:</b>	TO-263-3, D <sup>2</sup> Pak (2 Leads + Tab), TO-263AB
<b>Operating Temperature - Junction:</b>	-55°C ~ 150°C
<b>Mounting Type:</b>	Surface Mount
<b>Diode Type:</b>	Standard
<b>Current - Reverse Leakage @ Vr:</b>	10µA @ 150V
<b>Current - Average Rectified (Io):</b>	8A
<b>Capacitance @ Vr, F:</b>	-

### Related products



**UGB8DT-E3/81**

DIODE GEN PURP 200V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ



**UGB8DT-E3/45**

DIODE GEN PURP 200V 8A TO263AB

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**UGB8BT-E3/45**

DIODE GEN PURP 100V 8A TO263AB

[Vishay Semiconductor Diodes Division](#)

RFQ



**UGB8CTHE3/81**

DIODE GEN PURP 150V 8A TO263AB

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**UGB8CT-E3/45**

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**UGB8BT-E3/81**

DIODE GEN PURP 100V 8A TO263AB

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### Guess You May Looking For



**SIT1602BC-33-33S-35.840000Y**

-20 TO 70C, 5032, 50PPM, 3.3V, 3

[SITIME](#)

RFQ



**SIT8008AI-73-33E-20.000000D**

OSC MEMS 20.0000MHZ LVCMS SMD

[SITIME](#)

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**SIT1602BI-13-30S-31.250000E**

-40 TO 85C, 2520, 50PPM, 3.0V, 3

[SITIME](#)

RFQ



**SIT8008AI-13-33E-66.660000D**

OSC MEMS 66.6600MHZ LVCMS SMD

[SITIME](#)

RFQ



**SIT1602BI-71-33E-18.432000D**

-40 TO 85C, 2016, 20PPM, 3.3V, 1

[SITIME](#)

RFQ



**SIT8008BI-23-33E-33.333330E**

OSC MEMS 33.33333MHZ LVCMS SMD

[SITIME](#)

RFQ



**SIT1602BI-71-30N-75.000000E**

-40 TO 85C, 2016, 20PPM, 3.0V, 7

[SITIME](#)

RFQ



**SIT1602BC-32-25N-10.000000Y**

-20 TO 70C, 5032, 25PPM, 2.5V, 1

[SITIME](#)

RFQ



**SIT1602BC-81-30N-33.330000Y**

-20 TO 70C, 7050, 20PPM, 3.0V, 3

[SITIME](#)

RFQ



**SIT1602BI-11-28N-25.000000E**

-40 TO 85C, 2520, 20PPM, 2.8V, 2

[SITIME](#)

RFQ